



Thermally-Enhanced High Power RF LDMOS FETs 180 W, 2110 – 2170 MHz

Description

The PTFB211803EL and PTFB211803FL are 180-watt LDMOS FETs intended for use in multi-standard cellular power amplifier applications in the 2110 to 2170 MHz frequency band. Features include input and output matching, high gain and thermally-enhanced packages with slotted or earless flanges. Manufactured with Infineon's advanced LDMOS process, these devices provide excellent thermal performance and superior reliability.

Two-carrier WCDMA 3GPP Drive-up V_{DD} = 30 V, I_{DQ} = 1.30 A, f = 2170 MHz, 3GPP

WCDMA, PAR = 8 dB, 10 MHz carrier spacing,

BW 3.84 MHz

IMD Up

Efficiency

IMD Low

43 45 47 49

37 39 41 43 4 Output Power (dBm)



- Efficiency = 55%
- Increased negative gate-source voltage range for improved performance in Doherty amplifiers
- Integrated ESD protection.
- Capable of handling 10:1 VSWR @ 30 V, 180 W (CW) output power
- Pb-free and RoHS compliant

RF Characteristics

-20

-25

-30

-35

-40

-45

-50

-55

-60

31 33 35 37 39

IMD (dBc) / ACPR (dBc)

Two-carrier WCDMA Measurements (not subject to production test–verified by design/characterization in Infineon test fixture) $V_{DD} = 30 \text{ V}$, $I_{DQ} = 1.3 \text{ A}$, $P_{OUT} = 40 \text{ W}$ average, $f_1 = 2135 \text{ MHz}$, $f_2 = 2145 \text{ MHz}$, 3GPP signal, channel bandwidth = 3.84 MHz, peak/average = 8 dB @ 0.01% CCDF

40

35

ACPR

Efficier

15

10

5

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Characteristic	Symbol	Min	Тур	Max	Unit
Gain	G _{ps}	_	17.5	_	dB
Drain Efficiency	ηD	_	29.5	—	%
Adjacent Channel Power Ratio	ACPR	_	-38	_	dBc

All published data at T_{CASE} = 25°C unless otherwise indicated

ESD: Electrostatic discharge sensitive d	evice—observe handling precautions!	
Data Sheet	1 of 14	Rev. OHDDËÈI EÏ EÌ



RF Characteristics (cont.)

Two-carrier WCDMA Measurements (tested in Infineon test fixture)

 V_{DD} = 30 V, I_{DQ} = 1.3 A, P_{OUT} = 38 W average, f_1 = 2165 MHz, f_2 = 2170 MHz, 3GPP signal, channel bandwidth = 3.84 MHz, peak/average = 7.5 dB @ 0.01% CCDF

Characteristic	Symbol	Min	Тур	Max	Unit
Gain	G _{ps}	16	17	_	dB
Drain Efficiency	ηD	28	29.5	_	%
Intermodulation Distortion	IMD		-32.5	-31.5	dBc
DC Characteristics			C		

DC Characteristics

Characteristic	Conditions	Symbol	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0 V$, $I_{DS} = 10 mA$	V _{(BR)DSS}	65	_	_	V
Drain Leakage Current	$V_{DS} = 28 \text{ V}, V_{GS} = 0 \text{ V}$	IDSS	_	_	1.0	μA
Drain Leakage Current	$V_{DS} = 63 \text{ V}, V_{GS} = 0 \text{ V}$	IDSS	_	_	10.0	μA
On-State Resistance	V_{GS} = 10 V, V_{DS} = 0.1 V	R _{DS(on)}	_	0.05	_	Ω
Operating Gate Voltage	V _{DS} = 30 V, I _{DQ} = 1.3 A	V _{GS}	2.3	3.0	3.3	V
Gate Leakage Current	$V_{GS} = 10 \text{ V}, V_{DS} = 0 \text{ V}$	I _{GSS}	_	_	1.0	μA

Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	65	V
Gate-Source Voltage	V _{GS}	-6 to +10	V
Junction Temperature	TJ	200	°C
Storage Temperature Range	T _{STG}	-40 to +150	°C
Thermal Resistance (T _{CASE} = 70°C, 180 W CW)	$R_{ ext{ heta}JC}$	0.3	°C/W

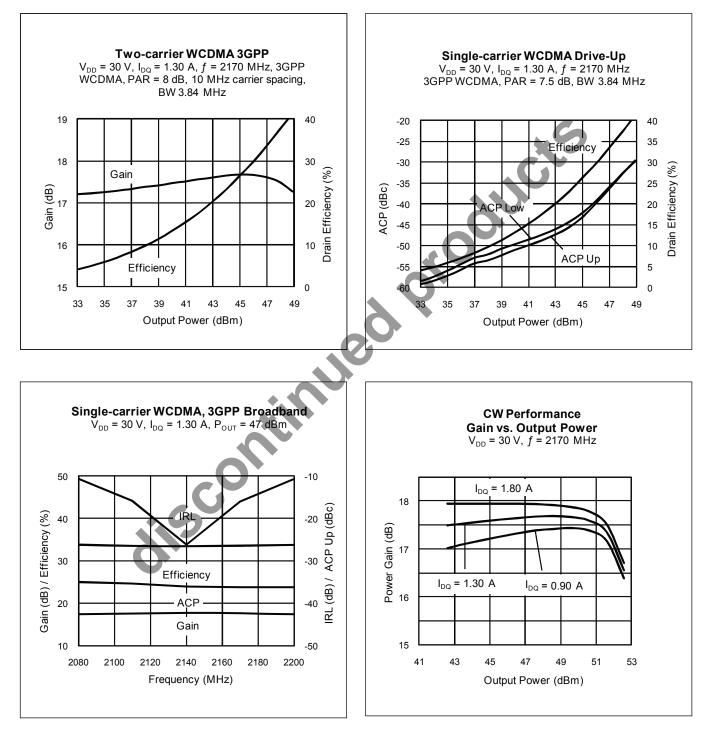
Ordering Information

Type and Version	Order Code	Package Description	Shipping
PTFB211803EL V1 R0	PTFB211803ELV1R0XTMA1	H-33288-6, bolt-down	Tape & Reel, 50pcs
PTFB211803EL V1 R250	PTFB211803ELV1R250XTMA1	H-33288-6, bolt-down	Tape & Reel, 250 pcs
PTFB211803FL V2 R0	PTFB211803FLV2R0XTMA1	H-34288-4/2, earless flange	Tape & Reel, 50pcs
PTFB211803FL V2 R250	PTFB211803FLV2R250XTMA1	H-34288-4/2, earless flange	Tape & Reel, 250 pcs

Data Sheet



Typical Performance (data taken in a production test fixture)

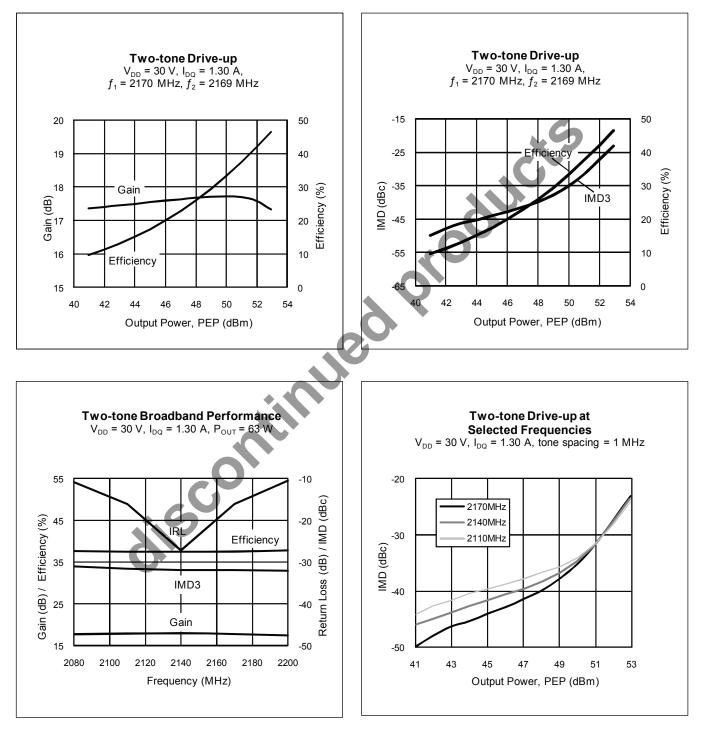


Data Sheet



PTFB211803EL PTFB211803FL

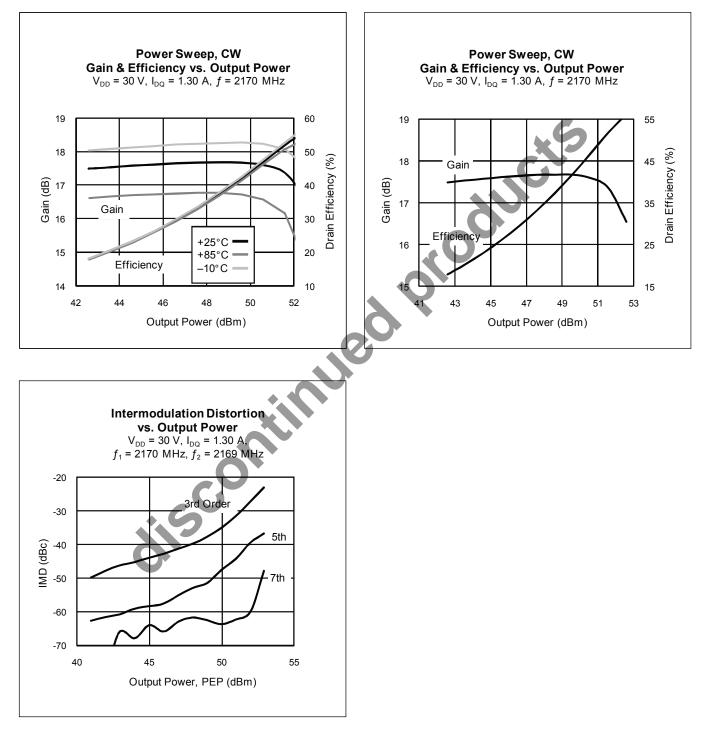
Typical Performance (cont.)





PTFB211803EL PTFB211803FL

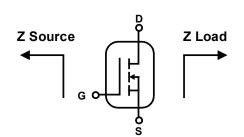
Typical Performance (cont.)



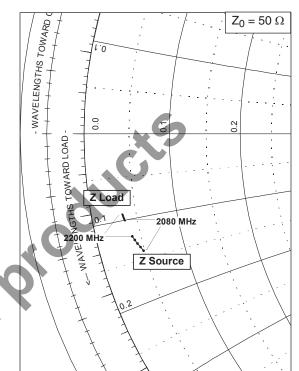


PTFB211803EL PTFB211803FL

Broadband Circuit Impedance



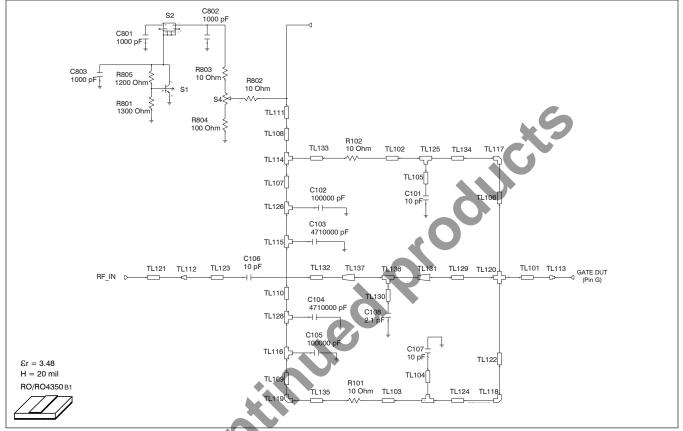
Frequency	Z So	urce Ω	Z Lo	ad Ω
MHz	R	jХ	R	jХ
2200	2.02	-6.03	1.70	-4.67
2170	2.12	-6.26	1.72	-4.76
2140	2.23	-6.50	1.73	-4.85
2110	2.34	-6.75	1.75	-4.95
2080	2.47	-7.01	1.77	-5.05



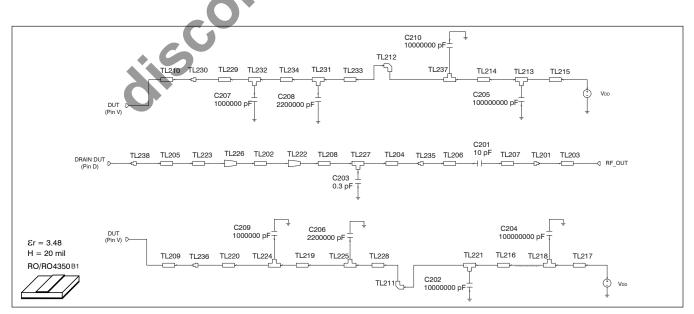
See next page for reference circuit information



Reference Circuit



Reference circuit input schematic for f = 2170 MHz



Reference circuit output schematic for f = 2170 MHz

Data Sheet



Description	
DUT	PTFB211803EL or PTFB211803FL
PCB	0.508 mm [.020"] thick, εr = 3.66, Rogers 4350, 1 oz. copper

Electrical Characteristics at 2170 MHz				
Transmission	Electrical	Dimensions: mm	Dimensions: mils	
Line	Characteristics			
Input				
TL101	0.053 λ, 6.67 Ω	W = 13.970, L = 4.064	W = 550, L = 160	
TL102, TL103	0.019 λ, 54.17 Ω	W = 1.016, L = 1.575	W = 40, L = 62	
TL104, TL105	0.000 λ, 36.77 Ω	W = 1.829, L = 0.025	W = 72, L = 1	
TL106, TL122	0.026 λ, 54.17 Ω	W = 1.016, L = 2.159	W = 40, L = 85	
TL107	0.021 λ, 54.17 Ω	W = 1.016, L = 1.727	W = 40, L = 68	
TL108	0.018 λ, 54.17 Ω	W = 1.016, L = 1.524	W = 40, L = 60	
TL109	0.029 λ, 54.17 Ω	W = 1.016, L = 2.451	W = 40, L = 97	
TL110	0.092 λ, 63.89 Ω	W = 0.762, L = 7.831	W = 30, L = 308	
TL111	0.031 λ, 34.72 Ω	W = 1.981, L = 2.540	W = 78, L = 100	
TL112		W1 = 1.270, W2 = 2.286	W1 = 50, W2 = 90	
TL113		W1 = 17.780, W2 = 12.700	W1 = 700, W2 = 500	
TL114	0.012 λ, 54.17 Ω	W1 = 1.016, W2 = 1.270, W3 = 1.016	W1 = 40, W2 = 50, W3 = 40	
TL115, TL116, TL126,	0.019 λ, 63.89 Ω	W1 = 0.762, W2 = 0.762, W3 = 1.600	W1 = 30, W2 = 30, W3 = 63	
TL128				
TL117, TL118, TL119		W = 1.016	W = 40	
TL120		W1 = 13.970, W2 = 1.016, W3 = 13.970	W1 = 550, W2 = 40, W3 = 550	
		W4 = 1.016	W4 = 40	
TL121	0.032 λ, 47.12 Ω	W = 1.270, L = 2.692	W = 50, L = 106	
TL123	0.016 λ, 31.24 Ω	W = 2.286, L = 1.270	W = 90, L = 50	
TL124, TL134	0.095 λ, 54.17 Ω	W = 1.016, L = 8.001	W = 40, L = 315	
TL125, TL127	0.022 λ, 54.17 Ω	W1 = 1.016, W2 = 1.016, W3 = 1.829	W1 = 40, W2 = 40, W3 = 72	
TL129	0.005 λ, 6.67 Ω	W = 13.970, L = 0.356	W = 550, L = 14	
TL130	0.000 λ, 144.35 Ω	W = 0.025, L = 0.025	W = 1, L = 1	
TL131 (taper)	0.008 $\lambda,$ 6.67 Ω / 7.64 Ω	W1 = 13.970, W2 = 12.065, L = 0.584	W1 = 550, W2 = 475, L = 23	
TL132	0.134 λ, 47.12	W = 1.270, L = 11.151	W = 50, L = 439	
TL133	0.012 λ, 54.17	W = 1.016, L = 1.016	W = 40, L = 40	
TL135	0.012 λ, 54.17	W = 1.016, L = 1.021	W = 40, L = 40	
TL136	0.000 λ, 7.64	W1 = 12.065, W2 = 12.065, W3 = 0.025	W1 = 475, W2 = 475, W3 = 1	
TL137 (taper)	0.032 $\lambda,$ 7.64 Ω / 47.12 Ω	W1 = 12.065, W2 = 1.270, L = 2.464	W1 = 475, W2 = 50, L = 97	

table continued on page 9



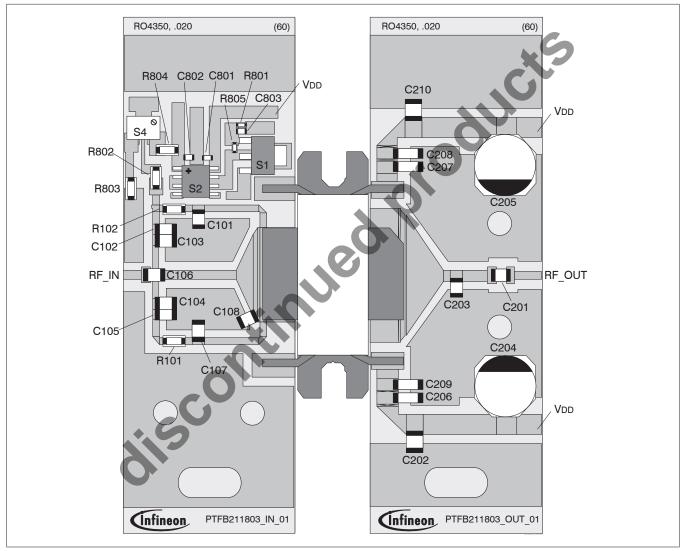
Transmission	Electrical	Dimensions: mm	Dimensions: mils
Line	Characteristics		
Output			
TL201		W1 = 1.270, W2 = 2.540	W1 = 50, W2 = 100
TL202	0.001 λ, 5.33 Ω	W = 17.780, L = 0.076	W = 700, L = 3
TL203	0.047 λ, 47.12 Ω	W = 1.270, L = 3.912	W = 50, L = 154
TL204	0.044 λ, 39.51 Ω	W = 1.651, L = 3.581	W = 65, L = 141
TL205	0.054 λ, 4.84 Ω	W = 19.685, L = 4.064	W = 775, L = 160
TL206, TL207	0.016 λ, 28.85 Ω	W = 2.540, L = 1.270	W = 100, L = 50
TL208	0.012 λ, 39.51 Ω	W = 1.651, L = 1.016	W = 65, L = 40
TL209	0.032 λ, 16.90 Ω	W = 4.928, L = 2.540	W = 194, L = 100
TL210	0.032 λ, 17.05 Ω	W = 4.877, L = 2.540	W = 192, L = 100
TL211, TL212		W = 3.048	W = 120
TL213, TL218	0.038 λ, 25.04 Ω	W1 = 3.048, W2 = 3.048, W3 = 3.048	W1 = 120, W2 = 120, W3 = 120
TL214, TL216	0.135 λ, 25.04 Ω	W = 3.048, L = 10.820	W = 120, L = 426
TL215, TL217	0.046 λ, 25.04 Ω	W = 3.048, L = 3.683	W = 120, L = 145
TL219, TL228, TL233, TL234	0.003 λ, 25.04 Ω	W = 3.048, L = 0.254	W = 120, L = 10
TL220, TL229	0.016 λ, 25.04 Ω	W = 3.048, L = 1.270	W = 120, L = 50
TL221, TL237	0.031 λ, 25.04 Ω	W1 = 3.048, W2 = 3.048, W3 = 2.489	W1 = 120, W2 = 120, W3 = 98
TL222 (taper)	0.074 $\lambda,$ 5.33 Ω / 39.51 Ω	W1 = 17.780, W2 = 1.651, L = 5.588	W1 = 700, W2 = 65, L = 220
TL223	0.003 λ, 4.84 Ω	W = 19.685, L = 0.254	W = 775, L = 10
TL224, TL225, TL231, TL232	0.022 λ, 25.04 Ω	W1 = 3.048, W2 = 3.048, W3 = 1.778	W1 = 120, W2 = 120, W3 = 70
TL226 (taper)	0.010 λ, 4.84 Ω / 5.33 Ω	W1 = 19.685, W2 = 17.780, L = 0.762	W1 = 775, W2 = 700, L = 30
TL227	0.022 λ,39.51 Ω	W1 = 1.651, W2 = 1.651, W3 = 1.829	W1 = 65, W2 = 65, W3 = 72
TL230, TL236		W1 = 4.928, W2 = 3.048,	W1 = 194, W2 = 120
TL235		W1 = 1.651, W2 = 2.540	W1 = 65, W2 = 100
TL238		W1 = 12.700, W2 = 17.780	W1 = 500, W2 = 700



Circuit Assembly Information

Test Fixture Part No.	LTN/PTFB211803EF

Find Gerber files for this test fixture on the Infineon Web site at http://www.infineon.com/rfpower



Reference circuit assembly diagram (not to scale)

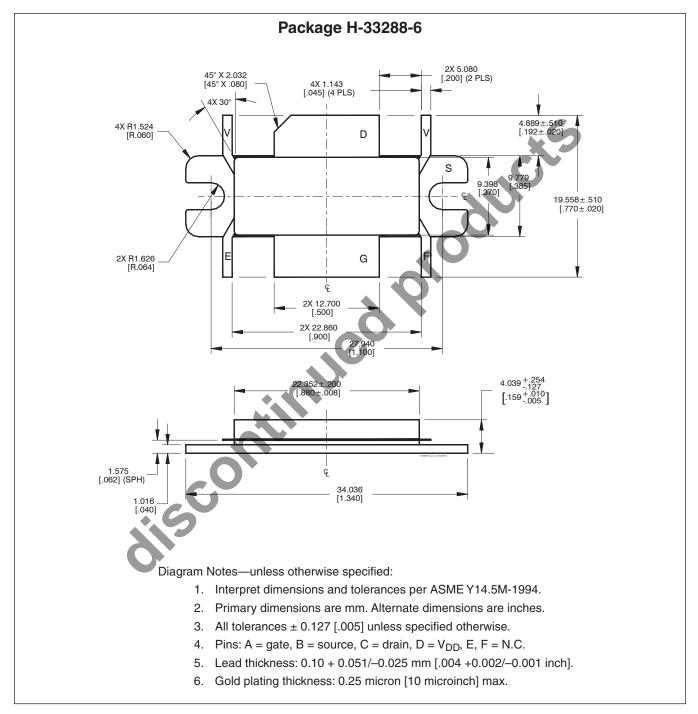


Components Information

Component	Description	Suggested Manufacturer	P/N
Input			
C101, C106, C107	Chip capacitor,10 pF	ATC	ATC100B100JW500XJ
C102, C105	Chip capacitor, 0.1 µF	Digi-Key	PCC104BCT-ND
C103, C104	Chip capacitor, 4.71 µF	Digi-Key	493-2372-2-ND
C108	Chip capacitor, 2.1 pF	ATC	ATC100B2R1BW500XB
C801, C802, C803	Capacitor, 1000 pF	Digi-Key	PCC1772CT-ND
R101, R102, R802, R803	Resistor, 10 Ω	Digi-Key	P10ECT-ND
R801	Resistor, 1300 Ω	Digi-Key	P1.3KGCT-ND
R804	Resistor, 100 Ω	Digi-Key	P100ECT-ND
R805	Resistor, 1200 Ω	Digi-Key	P1.2KGCT-ND
S1	Transistor	Digi-Key	BCP56-ND
S2	Voltage Regulator	Digi-Key	LM78L05ACM-ND
S4	Potentiometer, 2k Ω	Digi-Key	3224W-202ECT-ND
	·		·
Output			
C201	Chip capacitor, 10 pF	ATC	ATC100B100JW500XJ
C202, C210	Capacitor, 10 µF	Digi-Key	587-1818-2-ND
C203	Chip capacitor, 0.3 pF	ATC	ATC100B0R3BW500XB
C204, C205	Capacitor, 100 µF	Digi-Key	PCE4442TR-ND
C206, C208	Chip capacitor, 2.2 µF	Digi-Key	445-1447-2-ND
C207, C209	Chip capacitor, 1 µF	Digi-Key	445-1411-2-ND

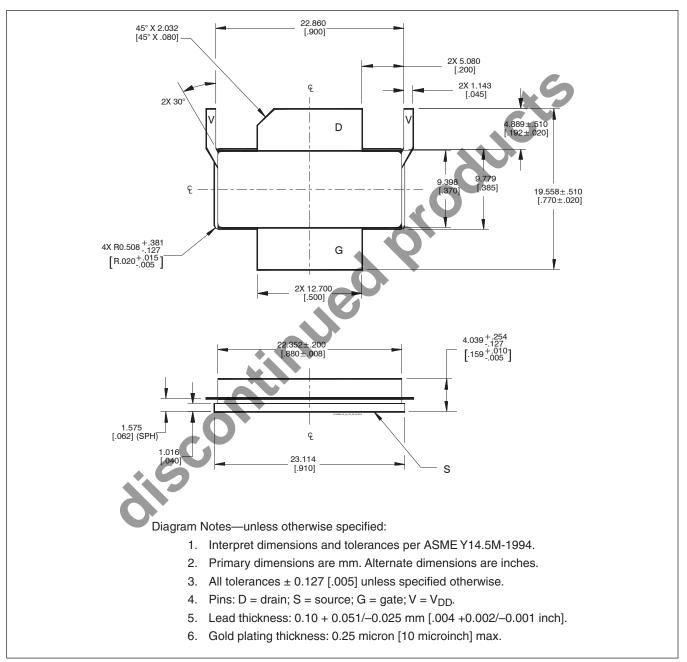


Package Outline Specifications





Package Outline Specifications (cont.)



Package H-34288-4/2

Find the latest and most complete information about products and packaging at the Infineon Internet page http://www.infineon.com/rfpower

PTFB211803EL V1 / PTFB211803FL V2

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Subjects (major changes since last revision)	
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